TECHNICAL DATA DATA SHEET 826, REV -

HERMETIC POWER MOSFET N-CHANNEL

FEATURES:

- 200 Volt, 0.045 Ohm, 50A MOSFET
- Hermetic Metal Package
- Low R_{DS (on)}

MAXIMUM RATINGS

ALL RATINGS ARE AT $T_{\rm C}$ = 25°C UNLESS OTHERWISE SPECIFIED.

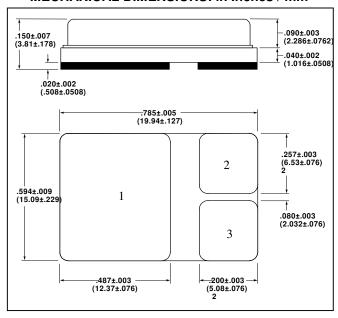
RATING	SYMBOL	MIN.	TYP.	MAX.	UNITS
GATE TO SOURCE VOLTAGE	V_{GS}	-	-	±20	Volts
ON-STATE DRAIN CURRENT	I _{D25}	-	-	50	Amps
PULSED DRAIN CURRENT	I_{DM}	-	-	200	Amps
OPERATING AND STORAGE TEMPERATURE	T_J/T_{STG}	-55	-	+150	°C
TOTAL DEVICE DISSIPATION	P _D	-	-	460	Watts
THERMAL RESISTANCE, JUNCTION TO CASE	$R_{\theta JC}$	-	-	0.27	°C/W

ELECTRICAL CHARACTERISTICS

DRAIN TO SOURCE BREAKDOWN VOLTAGE	BV _{DSS}	200	-	-	Volts
$V_{GS} = 0V, I_{D} = 250\mu A$					
STATIC DRAIN TO SOURCE ON STATE RESISTANCE	R _{DS(ON)}	-	-	0.045	Ω
$V_{GS} = 10V, I_D = 0.5I_{D25}$					
GATE THRESHOLD VOLTAGE $V_{DS} = V_{GS}$, $I_D = 4.0 \text{ mA}$	$V_{GS(th)}$	2.0	-	4.0	Volts
FORWARD TRANSCONDUCTANCE	g fs	26	32		S(1/Ω)
$V_{DS} = 10V, I_{D} = 0.5I_{D25}$				-	
ZERO GATE VOLTAGE DRAIN CURRENT					
$V_{DS} = 0.8 \text{ x Max. rating}, V_{GS} = 0V, T_{J} = 25^{\circ}C$	I _{DSS}	-	-	200	μΑ
$T_{J} = 125^{\circ}C$				1000	
GATE TO SOURCE LEAKAGE FORWARD $V_{GS} = 20V$	I _{GSS}	-	-	100	nA
GATE TO SOURCE LEAKAGE REVERSE V _{GS} = -20V				-100	
TURN ON DELAY TIME V _{DS} = 0.5V•	$t_{d(ON)}$	-	18	25	
RISE TIME V_{DSS} , $I_D = 0.5 \bullet I_{D25}$	t _r		15	20	nsec
TURN OFF DELAY TIME V _{GS} =10V	$t_{d(OFF)}$		72	90	
FALL TIME $V_{GS}=10V$	t _f		16	25	
DIODE FORWARD VOLTAGE $I_F = I_S$, $V_{GS} = 0V$	V _{SD}	_	_	1.5	Volts
Pulse test, $t \le 300 \mu s$, duty cycle d $\le 2 \%$	VSD			1.5	VOILS
REVERSE RECOVERY TIME T _{.1} = 25°C,					
$I_F=25A$, $V_R=100V$	t _{rr}	_	400	_	nsec
di/dt = 100A/µsec	۲rr		400		11300
	C _{iss}	_	4400	_	
OUTPUT CAPACITANCE $V_{GS} = 0 \text{ V},$ $V_{DS} = 25 \text{ V},$		_	800	_	pF
REVERSE TRANSFER CAPACITANCE f = 1.0MHz	C_{oss} C_{rss}		280		PΓ
TIEVEROE TRANSPER ON ASTRAINOE T = 1.000112	Orss		200		

DATA SHEET 826 REVISION -

MECHANICAL DIMENSIONS: in Inches / mm



SHD-6

PINOUT TABLE

DEVICE TYPE	PIN 1	PIN 2	PIN 3
MOSFET	DRAIN	SOURCE	GATE
SHD-6 PACKAGE			



TECHNICAL DATA

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